

STMUX1000L

GIGABIT LAN ANALOG SWITCH 16-BIT TO 8-BIT MULTIPLEXER

- LOW R_{ON}: 5.5 Ω TYPICAL
- V_{CC} OPERATING RANGE: 3.0 TO 3.6 V
 LOW CURRENT CONSUMPTION: 20 µA
- ESD HBM MODEL: > 2 KV
- CHANNEL ON CAPACITANCE: 7.5 pF TYPICAL
- SWITCHING TIME SPEED: 9 ns
- NEAR TO ZERO PROPAGATION DELAY: 250 ps
- VERY LOW CROSS TALK: -40 dB AT 250MHz
- BIT TO BIT SKEW: 200 ps
- > 450 MHZ -3db TYPICAL BANDWIDTH
- THREE SWITCH S.P.D.T FOR LED SUPPORTING
- PACKAGE: QFN56
- Pb FREE

DESCRIPTION

The STMUX1000L is a 16 to 8 Bit multiplexer/demultiplexer low R_{ON} bidirectional LAN Switch designed for various standard, such as 10/100/1000 Ethernet.



Table 1: Order Codes

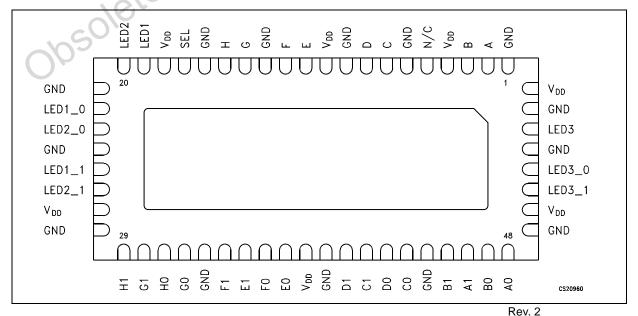
PACKAGE	T & R
QFN	STMUX1000LQTR

It is designed for very low Cross Talk, low bit to bit skew and low I/O capacitance.

The differential signal from the Gigabit Ethernet Transceiver is multiplexed in one of two selected output while the unselected switch go to Hi-Z status.

The device integrates three 16Ω switches, S.P.D.T. (Single Pole Dual Throw Channel), for LED supporting.

Figure 1: Pin Connection (Top Through View)



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Figure 2: Input Equivalent Circuit

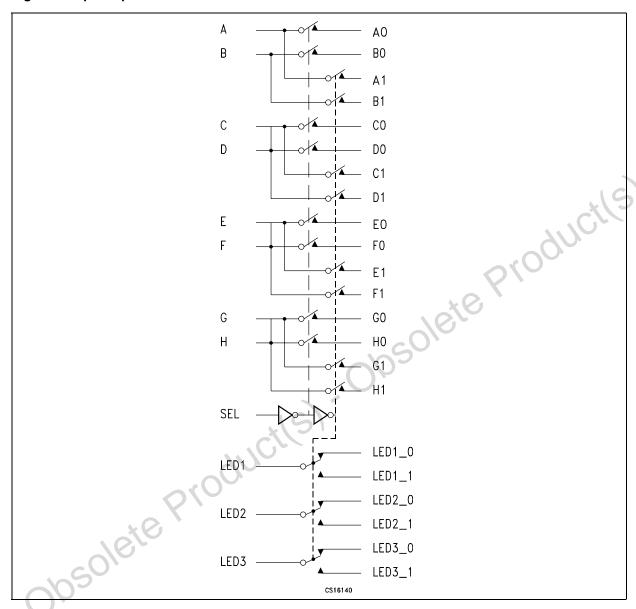


Table 2: Pin Description

PIN N°	SYMBOL	NAME AND FUNCTION
2, 3, 7, 8, 11, 12, 14, 15	A, B, C, D, E, F, G, H	8 Bit Bus
48, 47, 43, 42, 37, 36, 32, 31	A0, B0, C0, D0, E0, F0, G0, H0	8 Bit Multiplexed to Bus 0
46, 45, 41, 40, 35, 34, 30, 29	A1, B1, C1, D1, E1, F1, G1, H1	8 Bit Multiplexed to Bus 1
5	N/C	Not Connected
17	SEL	BUS and LED Switch Selection
19, 20, 54	LED1, LED2, LED3	LED Switch Input
22, 23, 25, 26, 51, 52	LED1_0, LED2_0, LED1_1, LED2_1, LED3_0, LED3_1	LED Switch Output
4, 10, 18, 27, 38, 50, 56	V_{DD}	Supply Voltage
1, 6, 9, 13, 16, 21, 24, 28, 33, 39, 44, 49, 53, 55	GND	Ground

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Table 3: Lan Switch Function Table

SE	FUNCTION
L	8 Bit Bus to 8 Bit Multiplexed Bus 0
Н	8 Bit Bus to 8 Bit Multiplexed Bus 1

Table 4: Led Switch Function Table

SE	FUNCTION
L	Led Switch Input connected to Led Switch Output X_0
Н	Led Switch Input connected to Led Switch Output X_1

Table 5: Absolute Maximum Ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage to Ground	-0.5 to 4	V
V _I	DC Input Voltage	-0.5 to 4	V
V _{IC}	DC Control Input Voltage	-0.5 to 4	V
Io	DC Output Current (*)	120	mA
P _D	Power Dissipation	0.5	W
T _{stg}	Storage Temperature	-65 to 150	°C
T _L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(*) If not exceed the max limit of P_D.

Table 6: DC Electrical Characteristics For Gigabit Ethernet LAN8/16MUX/DEMUX $(T_A = -40 \text{ to } 85^{\circ}\text{C}, V_{CC} = 3.3\text{V} \pm 10\%)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V_{IH}	Voltage Input High	High Level Guaranteed	2			V
V_{IL}	Voltage Input Low	Low Level Guaranteed	-0.5		0.8	V
V _{IK}	Clamp Diode Voltage	$V_{CC} = 3.6V, I_{IN} = -18mA$		-0.8	-1.2	V
I _{IH}	Input High Current	$V_{CC} = 3.6V$, $V_{IN} = V_{CC}$			±5	μΑ
I _{IL}	Input Low Current	$V_{CC} = 3.6V, V_{IN} = GND$			±5	μΑ
I _{OFF}	Power Down Leakage Current	V_{CC} = 0V, A to H V = 0V, A0 to H0 and A1 to H1 \leq 3.6V			±5	μА
R _{ON}	Switch ON Resistance (1)	V_{CC} = 3.0 V, V_{IN} = 1.5 to V_{CC} I_{IN} = -40mA		5.5	7.5	Ω
R _{FLAT}	ON Resistance FLATNESS (1, 2)	V_{CC} = 3.0 V, V_{IN} @ 1.5 and V_{CC} I_{IN} = -40mA		0.8		Ω
ΔR _{ON}	ON Resistance Match between channel $\Delta R_{ON} = R_{ONMAX} - R_{ONMIN} (1,3)$	$V_{CC} = 3.0 \text{ V}, V_{IN} = 1.5 \text{ to } V_{CC}$ $I_{IN} = -40 \text{mA}$		0.5	1	Ω

Note 1: Measured by voltage drop between Channels @ indicated current trough the switch. On-Resistance is determinate by the lower the Note 2: Flatness is defined as the difference the R_{ONMIN} and R_{ONMIN} of On-Resistance over the specified range condition. Note 3: ΔR_{ON} measured @ same V_{CC} , temperature and voltage level.

Table 7: DC Electrical Characteristics For 10/100 Ethernet LAN8/16MUX/DEMUX $(T_A = -40 \text{ to } 85^{\circ}\text{C}, V_{CC} = 3.3\text{V} \pm 10\%)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IH}	Voltage Input High	High Level Guaranteed	2			V
V _{IL}	Voltage Input Low	Low Level Guaranteed	-0.5		0.8	V
V _{IK}	Clamp Diode Voltage	V _{CC} = 3.6V, I _{IN} = -18mA		-0.7	-1.2	V
I _{IH}	Input High Current	$V_{CC} = 3.6V, V_{IN} = V_{CC}$			±5	μΑ
I _{IL}	Input Low Current	V _{CC} = 3.6V, V _{IN} = GND			±5	μΑ
I _{OFF}	Power Down Leakage Current	V_{CC} = 0V, A to H V = 0V, A0 to H0 and A1 to H1 \leq 3.6V			±5	μΑ
R _{ON}	Switch ON Resistance (1)	V_{CC} = 3.0 V, V_{IN} = 1.25 to V_{CC} I_{IN} = -40mA		5.5	7.5	Ω
R _{FLAT}	ON Resistance FLATNESS (1, 2)	V_{CC} = 3.0 V, V_{IN} @ 1.25 and V_{CC} I_{IN} = -40mA		0.9	AU	Ω
ΔR _{ON}	ON Resistance Match between channel $\Delta R_{\rm ON} = R_{\rm ONMAX} - R_{\rm ONMIN} (1, 3)$	$V_{CC} = 3.0 \text{ V}, V_{IN} = 1.25 \text{ to } V_{CC}$ $I_{IN} = -40 \text{mA}$		0.5	01	Ω

Note 1: Measured by voltage drop between Channels @ indicated current trough the switch. On-Resistance is determinate by the lower the voltage on the two.

Table 8: Led Switches DC Electrical Characteristics

 $(T_A = -40 \text{ to } 85^{\circ}\text{C}, V_{CC} = 3.3\text{V} \pm 10\%)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IH}	Voltage Input High	High Level Guaranteed	2			V
V _{IL}	Voltage Input Low	Low Level Guaranteed	-0.5		0.8	V
V _{IK}	Clamp Diode Voltage	$V_{CC} = 3.6V, I_{IN} = -18mA$		-0.7	-1.2	V
I _{IH}	Input High Current	$V_{CC} = 3.6V$, $V_{IN} = V_{CC}$			±5	μΑ
I _{IL}	Input Low Current	$V_{CC} = 3.6V, V_{IN} = GND$			±5	μΑ
R _{ON}	Switch ON Resistance (1)	V_{CC} = 3.0 V, V_{IN} = 1.25 to V_{CC} I_{IN} = -40mA		16	25	Ω
R _{FLAT}	ON Resistance FLATNESS (1, 2)	V_{CC} = 3.0 V, V_{IN} @ 1.25 and V_{CC} I_{IN} = -40mA		8		Ω
ΔR_{ON}	ON Resistance Match between channel $\Delta R_{ON} = R_{ONMAX}\text{-}R_{ONMIN} (1, 3)$	$V_{CC} = 3.0 \text{ V}, V_{IN} = 1.25 \text{ to } V_{CC}$ $I_{IN} = -40 \text{mA}$		1	2	Ω

Note 1: Measured by voltage drop between Channels @ indicated current trough the switch. On-Resistance is determinate by the lower the voltage on the two.

Note 2: Flatness is defined as the difference the R_{ONMAX} and R_{ONMIN} of On-Resistance over the specified range condition. Note 3: ΔR_{ON} measured @ same V_{CC} , temperature and voltage level.

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Note 3: ΔR_{ON} measured @ same V_{CC}, temperature and voltage level.

Table 9: Capacitance Lan 8/16 MUX/DEMUX $(T_A = 25$ °C, f = 1 MHz)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
C _{IN}	Input Capacitance (Note 4)	V _{IN} = 0 V		2	3	pF
C _{OFF}	Port x0 to Port x1, Switch Off (Note 4)	V _{IN} = 0 V		4	6	pF
C _{ON}	Capacitance Switch On (x to x0 or x to x1) (Note 4)	V _{IN} = 0 V		7.5	11	pF

Note 4: x = A to H, x0 = A0 to H0, x1 = A1 to H1.

Table 10: Capacitance Led Switches $(T_A = 25^{\circ}C, f = 1 \text{ MHz})$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0 V			10	pF
C _{OFF}	Port x0 to Port x1, Switch Off	V _{IN} = 0 V		4	10	pF
C _{ON}	Capacitance Switch On	V _{IN} = 0 V		11	20	pF

Table 11: Power Supply Characteristics $(T_A = -40 \text{ to } 85^{\circ}\text{C})$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CC}	Quiescent Power Supply	$V_{CC} = 3.6 \text{ V}, V_{IN} = V_{CC} \text{ or GND}$	710,	150	500	μΑ

Table 12: LAN 8/16 MUX/DEMUX Dynamic Electrical CharacteristicS

 $(T_A = -40 \text{ to } 85^{\circ}\text{C}, V_{CC} = 3.3\text{V} \pm 10\%)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Xtalk	Cross-Talk	$R_L = 100 \Omega, f = 250 MHz$		-40		dB
OIRR	Off Isolation	$R_L = 100 \Omega$, $f = 250 MHz$		-36		dB
BW	-3dB Bandwidth	R _L = 100 Ω		450		MHz

Table 13: LAN 8/16 MUX/DEMUX Switching Characteristics

 $(T_A = -40 \text{ to } 85^{\circ}\text{C}, V_{CC} = 3.3\text{V} \pm 10\%)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{PD}	Propagation Delay	V _{CC} = 3 V to 3.6 V		0.25		ns
t _{PZH} ,	Line Enable Time, SE to x to x0 or x to x1	V _{CC} = 3 V to 3.6 V	0.5	6.5	9	ns
t _{PHZ} , t _{PLZ}	Line Disable Time, SE to x to x0 or x to x1	V _{CC} = 3 V to 3.6 V	0.5	6.5	8.5	ns
t _{SK(O)}	Output Skew between center port to any other port	V _{CC} = 3 V to 3.6 V		0.1	0.2	ns
t _{SK(P)}	Skew between opposite transition of the same output (t _{PHL} , t _{PLH})	V _{CC} = 3 V to 3.6 V		0.1	0.2	ns

Note 4: x = A to H, x0 = A0 to H0, x1 = A1 to H1.

Table 14: Three Channel Switches Switching Characteristics

 $(T_A = -40 \text{ to } 85^{\circ}\text{C}, V_{CC} = 3.3\text{V} \pm 10\%)$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
t _{ON}	Propagation Delay	V _{CC} = 3 V to 3.6 V			50	ns
t _{OFF}	Propagation Delay	V _{CC} = 3 V to 3.6 V			30	ns

Figure 3: Bandwidth

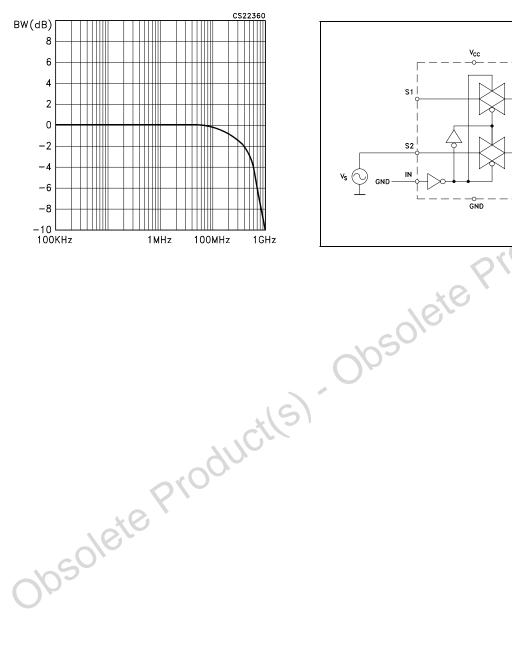
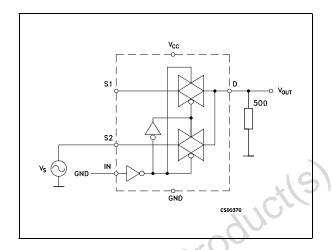


Figure 4: Schematic Bandwidth



QFN56 (11x5) MECHANICAL DATA

DIM.	mm.			inch			
DIN.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
А	0.70	0.75	0.80	0.028	0.030	0.031	
A1			0.05			0.002	
А3		0.20			0.008		
b	0.20	0.25	0.30	0.008	0.010	0.012	
D	10.90	11.00	11.10	0.429	0.433	0.437	
D2	8.30	8.40	8.50	0.327	0.331	0.335	
D3		9.50			0.374		
E	4.90	5.00	5.10	0.193	0.197	0.201	
E2	2.30	2.40	2.50	0.091	0.094	0.098	
E3		3.50		102	0.138		
е		0.50) .	0.020		
L	0.30	0.40	0.50	0.012	0.016	0.020	

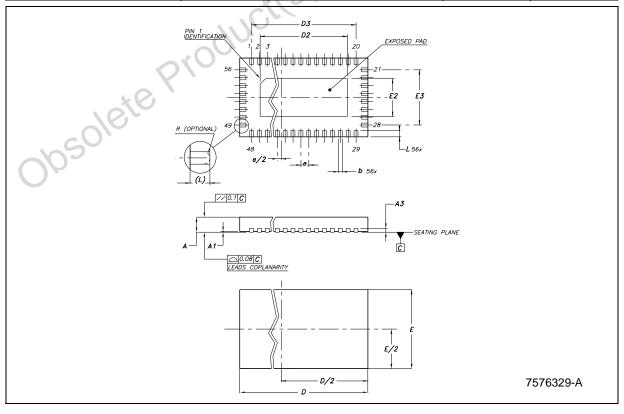


Table 15: Revision History

Date	Revision	Description of Changes
08-Apr-2005	1	First Release.
03-May-2005	2	Maturity Code.



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